CV

Ms Aneeqa Bashir

PERSONAL DETAILS:

Family Name:

First Name:

Nationality:

Date of Birth:

Bashir

Aneeqa

Pakistani

21st Sep 1977

Address: Department of Physics

University of the Punjab Quad-i-Azam Campus Lahore

Pakistan

Tel. Office: +92-99231243

E-mail: aneeqa.physics@pu.edu.pk

EDUCATION:

Ph.D: Experimental Solid state Physics, Oct 2007 to Oct 2011

Physics Department Imperial College London

Research Title: High performance ZnO Thin Film Transistors for

large area microelectronics

Supervisor: Dr. Thomas.D.Anthopoulos

Sponsored by: Higher Education Commission of Pakistan

M.Phil: Solid State Physics, Sep 2000 to May 2003

Centre for Solid State Physics University of the Punjab

Research Title: Investigation of PL spectra in InAs/GaAs

Quantum Dots

Supervisor: Dr. Arshad Saleem Bhatti

Marks: 86%

M.Sc: Physics, Sep 1997 to Aug 1999

Physics Department University of the Punjab

Special subject: Advanced Electronics

Marks: 78.6%

B.Sc Physics and mathematics, Sep 1994 to Aug 1996

Kinnaird College for Women Lahore

Marks: 68.3%

EMPLOYMENT:

28th May 2001 to

22nd Nov 2011: Lecturer in Physics Department, University of the Punjab Lahore

Duties: Teaching Solid State Physics to B.Sc and M.Sc Classes

having nearly 50 Students in each Class.

23rd Nov 2011 to date: Assistant Professor in Physics Department, University of the

Punjab Lahore

FOREIGN EXPOSURE:

25 April – 3 Aug 2005: Department of Material Sciences and Engineering, University of

Illinois, Urbana Champaign USA.

I have worked on Buffer Layer Assisted Growth (BLAG) for magnetic nanoparticles and also used TEM and AFM for

characterization.

17 May—17 Sep 2004: International Centre for Theoretical Physics (ICTP) Trieste, Italy

I have worked on Magneto Optic Kerr Effect (MOKE) for

magnetic nanoparticles

Oct 2007-Aug 2011 PhD Department of Physics, Imperial College London, UK

AWARDS:

May 2006: PhD Scholarship from Higher Education Commission of Pakistan

under faculty development program

Jan 2005: Fellowship for short term visit to Department of Material

Sciences and Engineering, UIUC USA from National Science

Foundation

Feb 2004: Fellowship for short term Research Program from ICTP, Italy

Feb 2000: One Year Fellowship for Diploma in Condensed Matter Physics

from ICTP, Italy. (did not avail)

CONFERENCES:

Dec 2011: International Conference on nanotechnology and nano ethics,

held at COMSATS Lahore Pakistan, oral presentation

March 2011: 7th International thin film transistors Conference, Cambridge UK,

Poster presentation.

September 2010: SID Organics electronics, UK, oral presentation

June 2009: E-MRS 2009 spring meeting held at Strasburg, France on

Advances in transparent electronics. Poster presentation

Sep 2008: 2nd SID (Society of information display, UK) conference at

Imperial College London, Poster presentation.

Oct 2006: International School on Thin Films and Surfaces held at

COMSATS Lahore Pakistan

July 2005: Physical Electronics held at Wisconsin, Madison USA

May 2004: Physics at nano-scale held at ICTP, Italy

June 2003: International Bhurbhan Conference on Wireless

Communications held at Bhurbhan Pakistan

Feb 2003: National Symposium on 'Frontiers in Physics' held at GC Lahore

Pakistan

PUBLICATIONS:

1. Aneeqa Bashir, Paul H. Wo"bkenberg, Jeremy Smith, James M. Ball, George Adamopoulos, Donal D. C. Bradley, and Thomas D. Anthopoulos. Adv. Mater. 2009, 21, 1–6.

- 2. George Adamopoulos, Aneeqa Bashir, Paul H. Wöbkenberg, Donal D. C. Bradley, and Thomas D. Anthopoulos. APP. Phys. Lett **95**, 133507,(2009).
- Aneeqa Bashir; Paul Wöbkenberg; Jeremy Smith; George Adamopoulos,; Donal Bradley; Thomas Anthopoulos;. 2009. Paper presented at EMRS Spring Meeting 2009, Strasbourg, France.
- Jeremy Smith; Aneeqa Bashir; George Adamopoulos; Donal Bradley; Thomas Anthopoulos. 2009. Paper presented at 2nd International Symposium on Flexible Organic Electronics, Thessaloniki, Greece.
- 5. Jeremy Smith, Aneeqa Bashir, George Adamopoulos, John E. Anthony, Donal D. C. Bradley, R. Hamilton, Martin Heeney, Iain McCulloch, and Thomas D. Anthopoulos. *Adv. Mater.* **2010**, *22*, 3598–3602.
- George Adamopoulos , Aneeqa Bashir , Stuart Thomas , William P. Gillin , Stamatis Georgakopoulos , Maxim Shkunov , Mohamed A. Baklar , Natalie Stingelin , Robert C. Maher , Lesley F. Cohen , Donal D. C. Bradley , and Thomas D. Anthopoulos. Adv. Mater. 2010, 22, 4764–4769.
- 7. George Adamopoulos, Aneeqa Bashir, William P. Gillin, Stamatis Georgakopoulos, Maxim Shkunov, Mohamed A. Baklar, Natalie Stingelin, Donal D. C. Bradley, and Thomas D. Anthopoulos. *Adv. Funct. Mater.* **2011**, *21*, 525–531

Patents

Thomas Anthopoulos, Donal Bradley, Aneeqa Bashir, Paul Henrich Wobkenberg, US Patent Application No. US/2011/0113859 A. Low voltage thin-film field effect transistors.

ADMINISTRATIVE RESPONSIBILITIES:

While working as a lecturer in physics Department University of the Punjab, I had been a member of Discipline Committee, Purchase Committee and Academic Council.